NSN 5962-01-540-5851

Memory Microcircuit - Page 1 of 1

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Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Features Provided:

3-state output

Inclosure Material:

Metal and oxide

Inclosure Configuration:

Pin grid array

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Current Rating Per Characteristic:

100.00 amperes forward current, nonrepetitive, peak total value microamperes

Product Name:

Fat page mode dram

Voltage Rating And Type Per Characteristic:

5.0 volts power source

Memory Device Type:

Ram

Memory Capacity:

128k x 8

Terminal Type And Quantity:

26 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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